Experimental study of the out-of-band emission from laser produced Sn plasma

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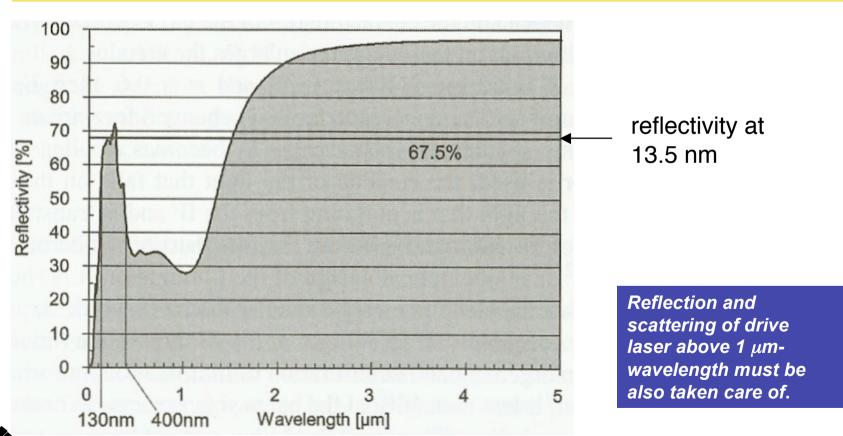
It is highly requested to clarify physics of OoB emission and provide experimental databases on it.

Joint requirement (EUV source WS/2006.5)

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130 - 400 nm: < 3 - 7 % (< 1% on wafer)

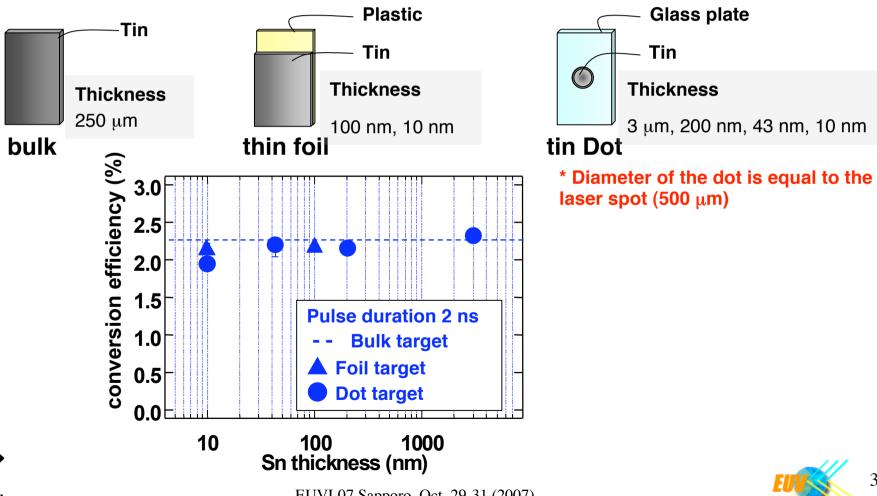
> 400 nm: < 0.3 - 3% (< 10 ~ 100% on wafer)





The minimum numbers of Sn atoms necessary for EUV pulse generation is $10^{14} \sim 10^{15}$. In other words, remaining mass can be a source of OoB emission.

EUV conversion efficiencies show no geometrical dependence for a give Sn mass.

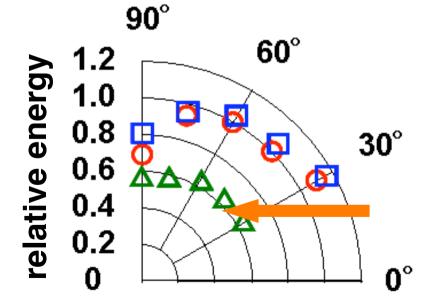


Angular distribution of OoB emission is rather isotropic. This result was used to derive absolute OoB energy.

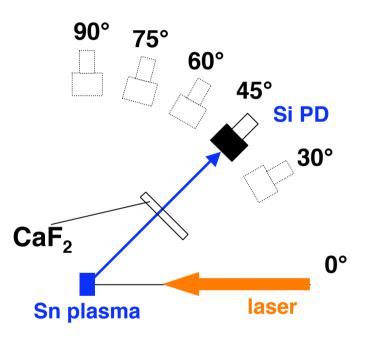
angular distribution

@130-550 nm, 8 ns pulse

- O 1-mm-thick bulk Sn
- □ 1-μm-thick Sn-coated plate
- Δ 1- μ m-thick Sn-coated sphere







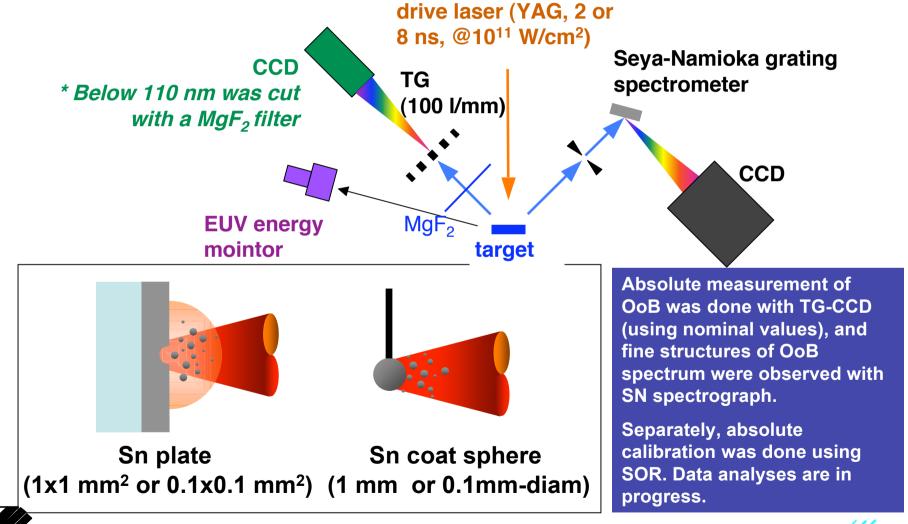
Sn target:

- 1-mm-thick plate
- 1-μm-thick plate
- **1-μm-thick coat sphere**





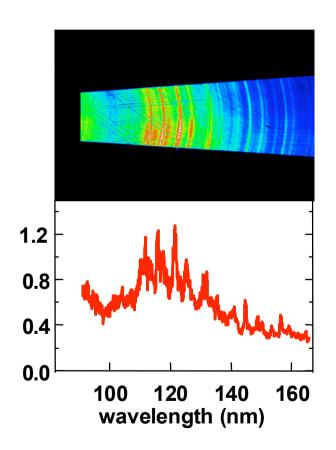
Dependence of OoB emission on target structures and sizes were investigated to identify the source region



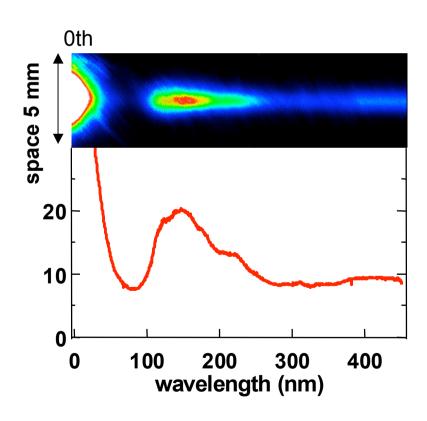
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Typical spectra from SN spectrograph and TG-CCD

from SN spectrograph



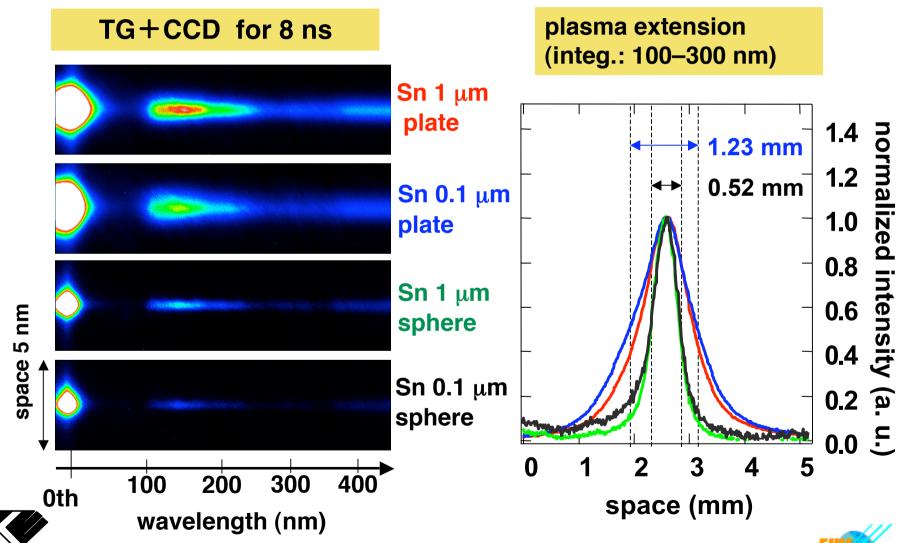
from TG-CCD







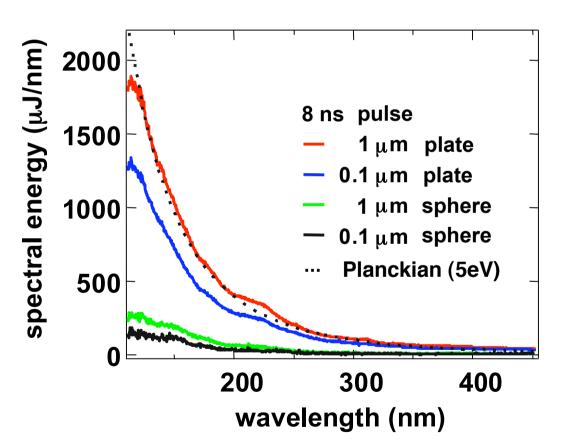
Size of OoB emission region is much wider for planar targets than those for spherical targets, inferring the source of OoB is in the surroundings of laser-spot.



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For 8-ns pulse drive, OoB emission energy from spherical targets is 20% or less of those from planar targets

OoB sepctra for 8-ns drive



fitting to Planck spectrum infers $T_R \sim 5 \text{ eV}$

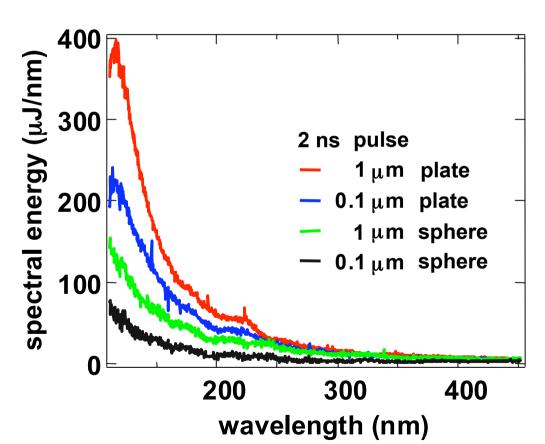
Further reduction of 40% is possible with decrease in the thickness of overcoat from 1 to 0.1 μm .





For 2-ns pulse drive, OoB emission energy from spherical targets is less than 25% of those from planar targets

OoB sepctra for 2-ns drive



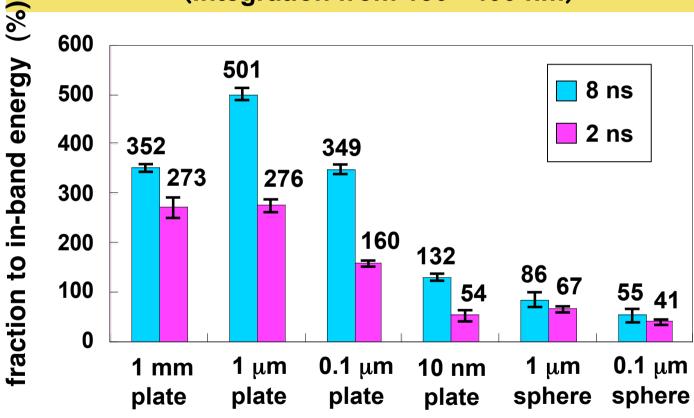
Further reduction of 50% is possible with decrease in the thickness of overcoat from 1 to 0.1 μm .





With decrease in Sn thickness and drive-pulse-duration, ratio of energy included in OoB emission to that in the in-band is substantially reduced.





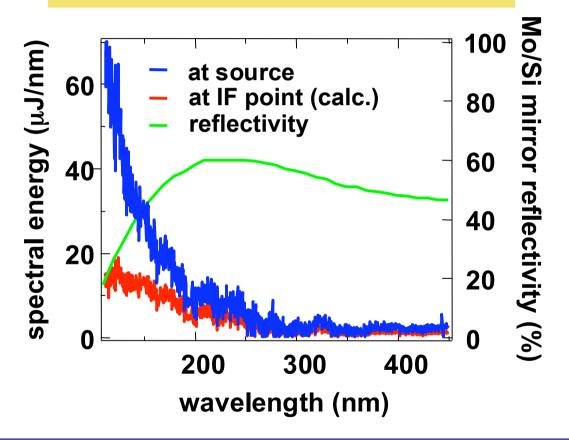
*reduction by the first-collection mirror is not included.





Spectral shape of OoB and reflectivity curve of collection mirror provide effective reflectivity of 31.5% for the 130-400 nm range.

Sn 0.1 μ m sphere w/ 2 ns pulse



Energy of OoB emission, in the range of 100 - 400 nm, is 2.78 mJ@source, corresponding to 1.14 mJ@IF or 22.1 % of 13.5-nm EUV. That is about three-times of the joint requirement value of 3-7%



Summary

Out-of-band (OoB) mission spectra in the VUV region (110-400 nm) was absolutely measured for laser produced Sn plasma.

- 1. With decrease in Sn overcoat thickness and duration of drive laser-pulse, OoB emission substantially decreases whereas conversion to the in-band is kept constant.
- 2. With decrease in target size down to that of the laser spot, OoB emission decreases, inferring the major source of OoB is in surroundings of the laser spot.
- 3. Emission energy in the 130-400 nm range at IF point is evaluated to be 22% of 13.5 nm EUV.

Use of minimum-mass target enables us to mitigate not only debris but also OoB emission.



